

# OH9249

## High Sensitivity Micropower Omnipolar Hall-Effect Switch

### Order Information

Part Number	Package	Temperature Range	Marking ID	Packing Type
OH9249-S	SOT23	-40 to 85°C	GJ9	Tape & Reel

**General Description:** The OH9249 is an ultra-sensitive Hall-effect switch with digital latched output, mainly designed for battery-operation, hand-held equipments. Special CMOS process is used for low-voltage and low-power requirement. A chopper stabilized amplifier improves stability of magnetic switch points. A sleep-awake logic controls the IC in sleep time or awake time. This function will reduce the average operating current of the IC. During the awake time, the output is changed with the magnetic flux density. During the sleep time, the output is latched in its previous state and the current consumption will reduce to some  $\mu$ A. The IC switching behaviour is omnipolar, either north or south pole sufficient strength will turn the output on. If the magnetic flux density is larger than operating point (BOP), the output will be turned on; if it is less than releasing point (BRP), the output will be turned off.



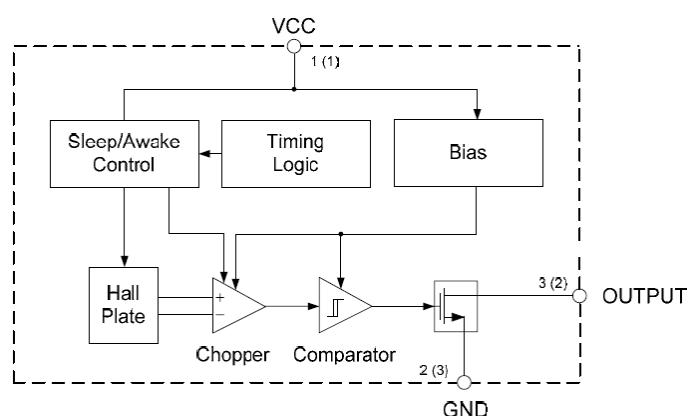
### Features

- Micropower Operation
- 2.5 to 5.5V Power Supply
- Switching for Both Poles of a Magnet (Omnipolar)
- Stabilized Chopper
- Superior Temperature Stability
- Digital Output Signal
- Built-in Pull-up Resistor
- ESD Rating: 4000V (Human Body Model)  
600V (Machine Model)

### Applications

- Cover Switch in Notebook PC/PDA
- Handheld Wireless Application Awake Switch
- Magnet Switch in Low Duty Cycle Applications

### Functional Block Diagram



### Absolute Maximum Ratings ( $T_A=25^\circ C$ )

Supply Voltage Vcc.....	7 V
Supply Current (Fault) Icc .....	6 mA
Output Voltage Vout .....	7 V
Output Current Iout .....	2 mA
Magnetic Flux Density B .....	Unlimited
Storage Temperature .....	-55 to 150 °C
Junction Temperature .....	150 °C

NOTE: Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

A (B)  
A for TO-92S-3  
B for SOT-23-3

# OH9249

## High Sensitivity Micropower Omnipolar Hall-Effect Switch

### Electrical Characteristics

V<sub>CC</sub> = 3V, T<sub>A</sub> = 25°C, unless otherwise specified

Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Supply Voltage	V <sub>CC</sub>		2.5	3	5.5	V
Supply Current	I <sub>AW</sub>	Awake		2	4	mA
	I <sub>SL</sub>	Sleep		6	10	µA
	I <sub>AVG</sub>	Average		10	15	µA
Output Current	I <sub>OUT</sub>				1.0	mA
Output Leakage Current	I <sub>LEAK</sub>	B <   BRP	-	<0.1	1.0	µA
Saturation Voltage	V <sub>SAT</sub>	I <sub>OUT</sub> = 1.0mA	-		0.4	V
Awake Mode Time	t <sub>AW</sub>	OPERATING		150		µs
Sleep Mode Time	t <sub>SL</sub>	OPERATING		90	120	ms
Duty Cycle	D			0.15		%
Chopper Frequency	f <sub>C</sub>			15		kHz

### Magnetic Characteristics

V<sub>CC</sub> = 3V, T<sub>A</sub> = 25°C, (1mT = 10 Gauss)

Parameter	symbol	Conditions	Value			Unit
			Min	Typ	Max	
Operate Point	B <sub>OPS</sub>	South pole to branded side B > B <sub>OPS</sub> , V <sub>OUT</sub> = low(output on)		30	55	GS
	B <sub>OPN</sub>	North pole to branded side B > B <sub>OPN</sub> , V <sub>OUT</sub> = low(output on)	-55	-30		GS
Release Point	B <sub>RPS</sub>	South pole to branded side B < B <sub>RPS</sub> , V <sub>OUT</sub> = high(output off)	5	20		GS
	B <sub>RPN</sub>	North pole to branded side B < B <sub>RPN</sub> , V <sub>OUT</sub> = high(output off)		-20	-5	GS
Hysteresis	B <sub>H</sub>	B <sub>OPX</sub> - B <sub>RPX</sub>	-	10	-	GS

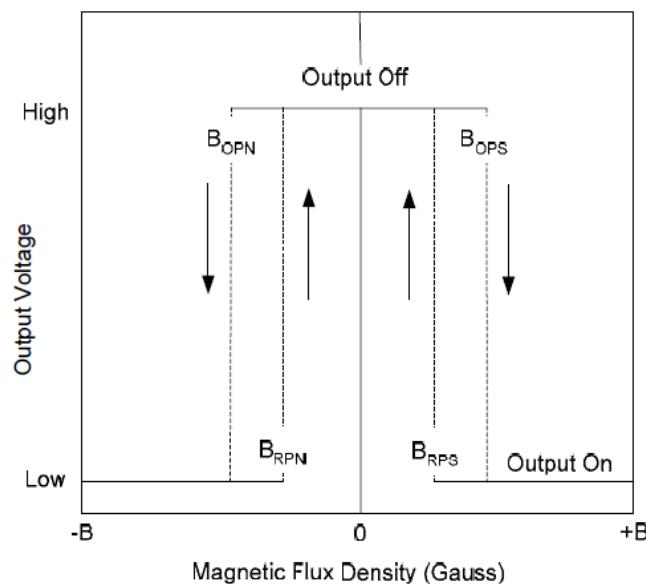
B<sub>OPX</sub> = operating point (output turns on);

B<sub>RPX</sub> = releasing point (output turns off)

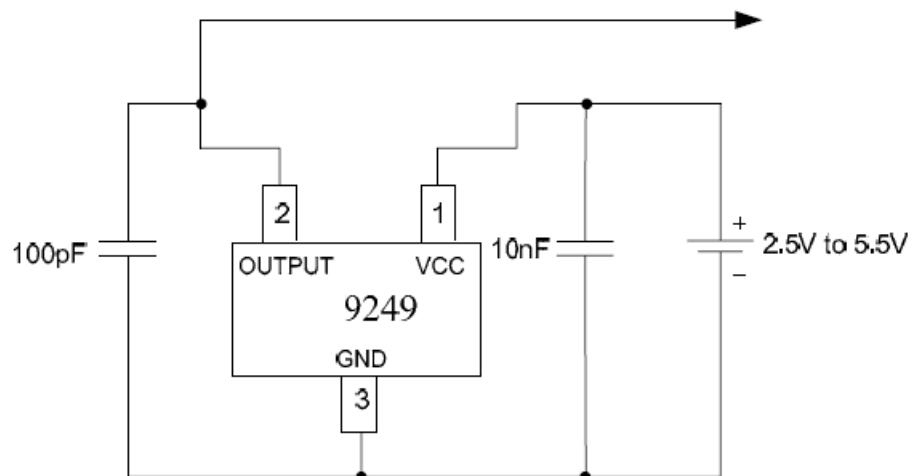
# OH9249

**High Sensitivity Micropower Omnipolar Hall-Effect Switch**

## Output Voltage vs. Magnetic Flux Density



## Typical Application



# OH9249

## **High Sensitivity Micropower Omnipolar Hall-Effect Switch**

### **Mechanical Dimension unit:mm(inch)**

SOT23

